




UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, Virginia 22313-1450
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/660,317	09/12/2000	Michael D. Camras	M-8633 US	6930
32566	7590	09/23/2004	EXAMINER	
PATENT LAW GROUP LLP 2635 NORTH FIRST STREET SUITE 223 SAN JOSE, CA 95134			LEWIS, MONICA	
			ART UNIT	PAPER NUMBER
			2822	

DATE MAILED: 09/23/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No. 09/660,317	Applicant(s) CAMRAS ET AL.	
	Examiner Monica Lewis	Art Unit 2822	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 06 June 2004.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-8, 10-27, 30-36, 43-46 and 51-80 is/are pending in the application.
- 4a) Of the above claim(s) 1-8, 10-27, 30-36, 43-46, 51-59 and 74-80 is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 60-73 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 18 September 2002 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. _____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input checked="" type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date <u>8/04 and 6/04</u> . | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

1. This office action is in response to the amendment filed June 6, 2004.

Response to Arguments

2. Applicant's arguments with respect to claims 60-73 have been considered but are moot in view of the new ground(s) of rejection.

Double Patenting

3. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970); and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Art Unit: 2822

4. Claims 60-73 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 32-79 of copending Application No. 09/880,204. Although the conflicting claims are not identical, they are not patentably distinct from each other because they both deal with light emitting devices.

This is a provisional obviousness-type double patenting rejection because the conflicting claims have not in fact been patented.

In regards to claims 60-73, Camras et al. ("Camras") discloses the following:

a) a stack of semiconductor layers, active region, transparent bonding layer (See Claims 32-79).

Claim Rejections - 35 USC § 103

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

6. Claims 60-65 are rejected under 35 U.S.C. 103(a) as obvious over Jiang et al. (U.S. Patent No. 5,966,399) in view of Osenbach et al. *Low Cost/High Volume Laser Modules Using Silicon Optical Technology*.

In regards to claim 60, Jiang et al. ("Jiang") discloses the following:

a) a stack of layers including semiconductor layers comprising an active region (24) (For Example: See Figure 1); and

b) a transparent lens (44) attached to said stack (For Example: See Figure 1).

Art Unit: 2822

In regards to claim 60, Jiang fails to disclose the following:

a) a transparent bonding layer disposed between said lens and a surface of said stack, said transparent bonding layer bonding said lens to said stack, said transparent bonding layer comprising an inorganic material.

However, Osenbach et al. ("Osenbach") discloses ALO utilized as a bonding attachment for a lens (For Example: See Page 581). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Seki to include ALO as disclosed in Osenbach because it aids in providing extremely stable coupling over environmental extremes (For Example: See Pages 581-582).

Additionally, since Seki and Osenbach are both from the same field of endeavor, the purpose disclosed by Osenbach would have been recognized in the pertinent art of Seki.

In regards to claim 61, Jiang fails to disclose the following:

a) transparent bonding layer is formed from a material selected from the group of optical glass, chalcogenide glass, III-V semiconductors, II-VI semiconductors, group IV semiconductors, metals, metal oxides, metal fluorides, yttrium aluminum garnet, phosphides, arsenides, antimonides, nitrides, and combinations thereof.

However, Osenbach discloses ALO utilized as a bonding attachment for a lens (For Example: See Page 581). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Seki to include ALO as disclosed in Osenbach because it aids in providing extremely stable coupling over environmental extremes (For Example: See Pages 581-582).

Additionally, since Seki and Osenbach are both from the same field of endeavor, the purpose disclosed by Osenbach would have been recognized in the pertinent art of Seki.

Art Unit: 2822

In regards to claim 62, Jiang fails to disclose the following:

a) transparent bonding layer includes one or more luminescent materials that convert light of a wavelength emitted by said active region to at least another wavelength.

Although Osenbach fails to specifically disclose the limitations listed above, Applicant discloses that the bonding layer could be formed from metal oxides therefore Osenbach's bonding layer would have the same characteristics.

In regards to claim 63, Jiang fails to discloses the following:

a) bonding layer has a thickness less than about 500 Angstroms.

Additionally, the applicant has not established the critical nature of a bonding layer that has a thickness less than 500 Angstroms. "The law is replete with cases in which the difference between the claimed invention and the prior art is some range or other variable within the claims. . . . In such a situation, the applicant must show that the particular range is critical, generally by showing that the claimed range achieves unexpected results relative to the prior art range." *In re Woodruff*, 919 F.2d 1575, 16 USPQ2d 1934 (Fed. Cir.1990). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to have various ranges.

In regards to claim 64, Jiang discloses the following:

a) surface includes a surface of one of said semiconductor layers (For Example: See Figure 1).

In regards to claim 65, Jiang fails to discloses the following:

a) bonding layer has an index of refraction greater than about 1.5 for light emitted by said active region.

Although Osenbach fails to specifically disclose the limitations listed above, it appears that it is known that the refractive index of aluminum oxide can range from 1.0-2.65 (See Cerac Technical Publications).

7. Claims 66-68 are rejected under 35 U.S.C. 103(a) as obvious over Jiang et al. (U.S. Patent No. 5,966,399) in view of Osenbach et al. *Low Cost/High Volume Laser Modules Using Silicon Optical Technology* and Okazaki et al. (U.S. Patent No. 6,495,862).

In regards to claim 66, Jiang fails to disclose the following:

a) surface includes a surface of a transparent superstrate layer disposed above said semiconductor layers.

However, Okazaki et al. ("Okazaki") discloses utilizing a transparent substrate layer (For Example: See Column 14 Lines 1-13). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Jiang to include a transparent layer as disclosed in Okazaki because it aids in improving the external quantum efficiency (For Example: See Column 2 Lines 10-23).

Additionally, since Jiang and Sickmiller are both from the same field of endeavor, the purpose disclosed by Sickmiller would have been recognized in the pertinent art of Jiang.

In regards to claims 67 and 68, Jiang fails to disclose the following:

a) superstrate layer is formed from a material selected from the group of sapphire, SiC, GaN and GaP that has a refractive index for light emitted by said active region greater than about 1.8.

However, Okazaki discloses the use of sapphire (For Example: See Column 14 Lines 1-13). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Jiang to include a sapphire substrate as

Art Unit: 2822

disclosed in Okazaki because it aids in improving the external quantum efficiency (For Example: See Column 2 Lines 10-23).

Additionally, since Jiang and Sickmiller are both from the same field of endeavor, the purpose disclosed by Sickmiller would have been recognized in the pertinent art of Jiang.

8. Claim 71 is rejected under 35 U.S.C. 103(a) as obvious over Jiang et al. (U.S. Patent No. 5,966,399) in view of Osenbach et al. *Low Cost/High Volume Laser Modules Using Silicon Optical Technology* and Musk (U.S. Patent No. 4,983,009).

In regards to claim 71, Jiang fails to disclose the following:

a) lens is formed from a material selected from the group of zirconium oxide, sapphire, GaP, ZnS, materials containing lead oxide, materials containing tungsten oxide, and SiC.

However, Musk discloses utilizing a sapphire lens (For Example: See Column 3 Lines 49-51). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Jiang to include a sapphire lens as disclosed in Musk because it aids in providing a high refractive index (For Example: See Column 3 Lines 49-59).

Additionally, since Jiang and Musk are both from the same field of endeavor, the purpose disclosed by Musk would have been recognized in the pertinent art of Jiang.

9. Claim 72 is rejected under 35 U.S.C. 103(a) as obvious over Jiang et al. (U.S. Patent No. 5,966,399) in view of Osenbach et al. *Low Cost/High Volume Laser Modules Using Silicon Optical Technology* and Burgyan (U.S. Patent No. 4,109,054).

In regards to claim 72, Jiang fails to disclose the following:

a) transparent bonding layer includes a lead oxide.

Art Unit: 2822

However, Burgyan discloses utilizing lead oxide (For Example: See Derwent Abstract). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Jiang to include a lead oxide as disclosed in Musk because it aids in providing good bond strength (For Example: See Derwent Abstract).

Additionally, since Jiang and Burgyan are both from the same field of endeavor, the purpose disclosed by Burgyan would have been recognized in the pertinent art of Jiang.

10. Claim 73 is rejected under 35 U.S.C. 103(a) as obvious over Jiang et al. (U.S. Patent No. 5,966,399) in view of Osenbach et al. *Low Cost/High Volume Laser Modules Using Silicon Optical Technology* and Sato (Japanese Patent No. 355065473).

In regards to claim 73, Jiang fails to disclose the following:

a) transparent bonding layer includes a tungsten oxide.

However, Sato discloses utilizing tungsten oxide (For Example: See Abstract). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Jiang to include a tungsten oxide as disclosed in Musk because it aids in providing good bond strength (For Example: See Abstract).

Additionally, since Jiang and Sato are both from the same field of endeavor, the purpose disclosed by Sato would have been recognized in the pertinent art of Jiang.

Conclusion

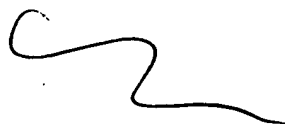
11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Monica Lewis whose telephone number is 571-272-1838.

Art Unit: 2822

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone number for the organization where this application or proceeding is assigned is 703-308-7722 for regular and after final communications. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

ML

September 14, 2004



Mary Wilczewski
Primary Examiner